

Mark: 2J

## **PNP Switching Transistor**

This device is designed for very high speed saturated switching at collector currents to 100 mA. Sourced from Process 65. See PN4258 for characteristics.

#### Absolute Maximum Ratings\* TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units |
|-----------------------------------|--|-------------|-------|
| V <sub>CEO</sub>                  | Collector-Emitter Voltage                        | 12          | V     |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 12          | V     |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 4.0         | V     |
| Ic                                | Collector Current - Continuous                   | 200         | mA    |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### NOTES:

 1) These ratings are based on a maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations. 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

### Thermal Characteristics TA = 25°C unless otherwise noted

| Symbol          | Characteristic                          | Мах    |           | Units |
|-----------------|---|--------|-----------|-------|
|                 |   | PN3640 | *MMBT3640 |       |
| P <sub>D</sub>  | Total Device Dissipation                | 350    | 225       | mW    |
|                 | Derate above 25°C                       | 2.8    | 1.8       | mW/∘C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case    | 125    |           | °C/W  |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 357    | 556       | °C/W  |

\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

PN3640 / MMBT3640

# PNP Switching Transistor

| Symbol  | Parameter   | Test Conditions  | Min         | Max  | Units   |
|---|---|--|-------------|--|---|
|   |   |  |             |  |   |
|   | RACTERISTICS  |  |             |  |   |
| / <sub>(BR)CEO</sub>  | Collector-Emitter Breakdown Voltage*  | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$   | 12          |  | V   |
| / <sub>(BR)CES</sub>  | Collector-Emitter Breakdown Voltage   | $I_{C} = 100 \ \mu A, \ V_{BE} = 0$  | 12          |  | V   |
| (BR)CBO   | Collector-Base Breakdown Voltage  | $I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$   | 12          |  | V   |
| / <sub>(BR)EBO</sub>  | Emitter-Base Breakdown Voltage  | $I_{E} = 100 \ \mu A, I_{C} = 0$   | 4.0         |  | V   |
| CES   | Collector Cutoff Current  | $V_{CE} = 6.0 \text{ V}, V_{BE} = 0$   |             | 0.01<br>1.0  | μΑ  |
| В   | Base Current  | $V_{CE} = 6.0 \text{ V}, V_{BE} = 0, T_A = 65^{\circ}\text{C}$<br>$V_{CE} = 6.0 \text{ V}, V_{BE} = 0$   |             | 1.0  | μA<br>nA                                      |
| ,   |   |  |             |  |   |
| )N CHAR   | RACTERISTICS*   |  |             |  |   |
|   | DC Current Gain   | $I_{C} = 10 \text{ mA}, V_{CE} = 0.3 \text{ V}$  | 30          | 120  |   |
| FE  |   | $I_{\rm C} = 50$ mA, $V_{\rm CE} = 0.0$ V  | 20          | 120  |   |
| / <sub>CE(sat)</sub>  | Collector-Emitter Saturation Voltage  | $I_{\rm C} = 10$ mA, $I_{\rm B} = 0.5$ mA  |             | 0.3  | V   |
|   |   | $I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$<br>$I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$   |             | 0.2<br>0.6   | V<br>V  |
|   |   | $I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}, T_{A} = 65^{\circ}\text{C}$  |             | 0.25   | v   |
|   |   |  |             |  |   |
| BE(sat)   | Base-Emitter Saturation Voltage   | $I_{\rm C} = 10$ mA, $I_{\rm B} = 0.5$ mA  | 0.75        | 0.95   | V   |
|   | Base-Emitter Saturation Voltage   | $I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA}$<br>$I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$<br>$I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$  | 0.75<br>0.8 | 0.95<br>1.0<br>1.5   | V<br>V<br>V                                   |
| / <sub>BE(sat)</sub><br>SMALL SI  |   | $I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA}$ $I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$ $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$ $I_{C} = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$   |             | 1.0  | V   |
| SMALL SI  | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product  | $I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA}$ $I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$ $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$  | 0.8         | 1.0  | V<br>V  |
| SMALL SI<br>T<br>Cobo   | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product<br>Output Capacitance  | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5<br>3.5  | MHz<br>pF                                     |
| SMALL SI  | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product  | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5   | V<br>V<br>MHz                                 |
| SMALL SI<br>T<br>Cobo   | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product<br>Output Capacitance  | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5<br>3.5  | MHz<br>pF                                     |
| MALL SI   | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS   | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5<br>3.5  | MHz<br>pF                                     |
| MALL SI   | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS Delay Time  | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5<br>3.5  | MHz<br>pF                                     |
| MALL SI<br>Cobo<br>Cibo   | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS Delay Time Rise Time  | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5                                     | MHz<br>pF<br>pF                               |
| SMALL SI<br>Cobo<br>Cibo<br>SWITCHIN  | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS Delay Time Rise Time Storage Time                                   | $\begin{array}{l} I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{array}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10                               | MHz<br>pF<br>pF                               |
| SMALL SI<br>Pobo<br>Dibo<br>SWITCHIN  | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product<br>Output Capacitance<br>Input Capacitance<br>NG CHARACTERISTICS<br>Delay Time<br>Rise Time<br>Storage Time<br>Fall Time | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30                         | MHz<br>pF<br>pF<br>ns<br>ns                   |
| SMALL SI<br>r<br>Pobo<br>Pibo<br>SWITCHIN<br>d<br>r<br>s<br>f   | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS Delay Time Rise Time Storage Time                                   | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{split}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30<br>20                   | MHz<br>pF<br>pF<br>ns<br>ns<br>ns             |
| SMALL SI<br>Pobo<br>Sibo<br>SWITCHIN  | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product<br>Output Capacitance<br>Input Capacitance<br>NG CHARACTERISTICS<br>Delay Time<br>Rise Time<br>Storage Time<br>Fall Time | $\begin{split} I_{C} &= 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} &= 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \\ I_{C} &= 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \\ \end{split}$  | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30<br>20<br>12             | MHz<br>pF<br>pF<br>ns<br>ns<br>ns<br>ns       |
| SMALL SI<br>Pobo<br>Sibo<br>SWITCHIN  | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product<br>Output Capacitance<br>Input Capacitance<br>NG CHARACTERISTICS<br>Delay Time<br>Rise Time<br>Storage Time<br>Fall Time | $\begin{array}{l} I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{array}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30<br>20<br>12             | MHz<br>pF<br>pF<br>ns<br>ns<br>ns<br>ns       |
| SMALL SI<br>Pobo<br>Sibo<br>SWITCHIN  | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS Delay Time Rise Time Storage Time Fall Time Turn-On Time            | $\begin{array}{c} I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{array}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30<br>20<br>12<br>25       | MHz<br>pF<br>pF<br>ns<br>ns<br>ns<br>ns<br>ns |
| SMALL SI<br>Pobo<br>Dibo<br>Dibo<br>SWITCHIN<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S<br>S   | GNAL CHARACTERISTICS<br>Current Gain - Bandwidth Product<br>Output Capacitance<br>Input Capacitance<br>NG CHARACTERISTICS<br>Delay Time<br>Rise Time<br>Storage Time<br>Fall Time | $\begin{array}{l} I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{array}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30<br>20<br>12<br>25       | MHz<br>pF<br>pF<br>ns<br>ns<br>ns<br>ns<br>ns |
| SMALL SI<br>r<br>Cobo   | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS Delay Time Rise Time Storage Time Fall Time Turn-On Time            | $\begin{array}{l} I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \\ \hline \\ I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \hline \\ V_{CB} = 5.0 \text{ V}, I_{E} = 0, \\ f = 1.0 \text{ MHz} \\ \hline \\ V_{BE} = 0.5 \text{ V}, I_{C} = 0, \\ f = 1.0 \text{ MHz} \\ \hline \\ V_{CC} = 6.0 \text{ V}, V_{BE(off)} = 1.9 \text{ V}, \\ I_{C} = 50 \text{ mA}, I_{B1} = 5.0 \text{ mA} \\ \hline \\ V_{CC} = 6.0 \text{ V}, I_{C} = 50 \text{ mA}, \\ I_{B1} = I_{B2} = 5.0 \text{ mA} \\ \hline \\ V_{CC} = 6.0 \text{ V}, V_{BE(off)} = 1.9 \text{ V}, \\ I_{C} = 50 \text{ mA}, I_{B1} = 5.0 \text{ mA} \\ \hline \\ V_{CC} = 1.5 \text{ V}, I_{C} = 10 \text{ mA}, \\ I_{B1} = I_{B2} = 0.5 \text{ mA} \\ \hline \\ V_{CC} = 6.0 \text{ V}, V_{BE(off)} = 1.9 \text{ V}, \\ I_{C} = 50 \text{ mA}, I_{B1} = 5.0 \text{ mA} \\ \hline \end{array}$ | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30<br>20<br>12<br>25<br>60 | MHz<br>pF<br>pF<br>ns<br>ns<br>ns<br>ns<br>ns |
| SMALL SI<br>T<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo<br>Cobo | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance Input Capacitance NG CHARACTERISTICS Delay Time Rise Time Storage Time Fall Time Turn-On Time            | $\begin{array}{l} I_{C} = 10 \text{ mA}, I_{B} = 0.5 \text{ mA} \\ I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA} \\ I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA} \end{array}$   | 0.8         | 1.0<br>1.5<br>3.5<br>3.5<br>10<br>30<br>20<br>12<br>25<br>60 | MHz<br>pF<br>pF<br>ns<br>ns<br>ns<br>ns<br>ns |

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PN3640 / MMBT3640



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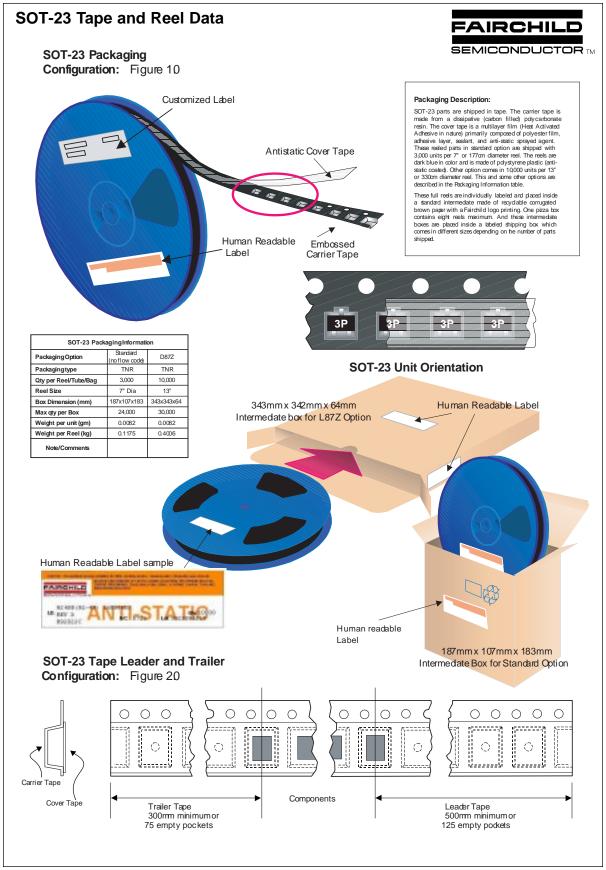
March 2001, Rev. B1





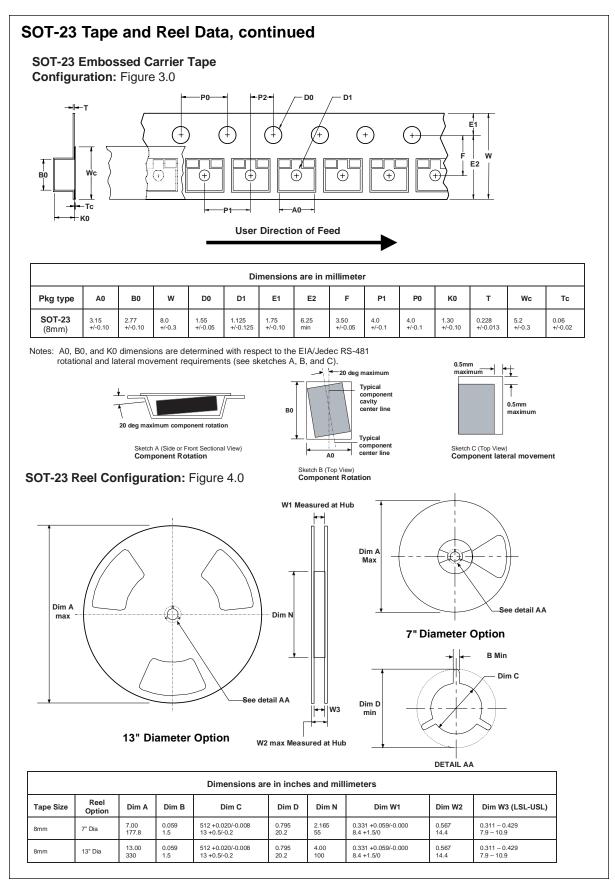
July 1999, Rev. A



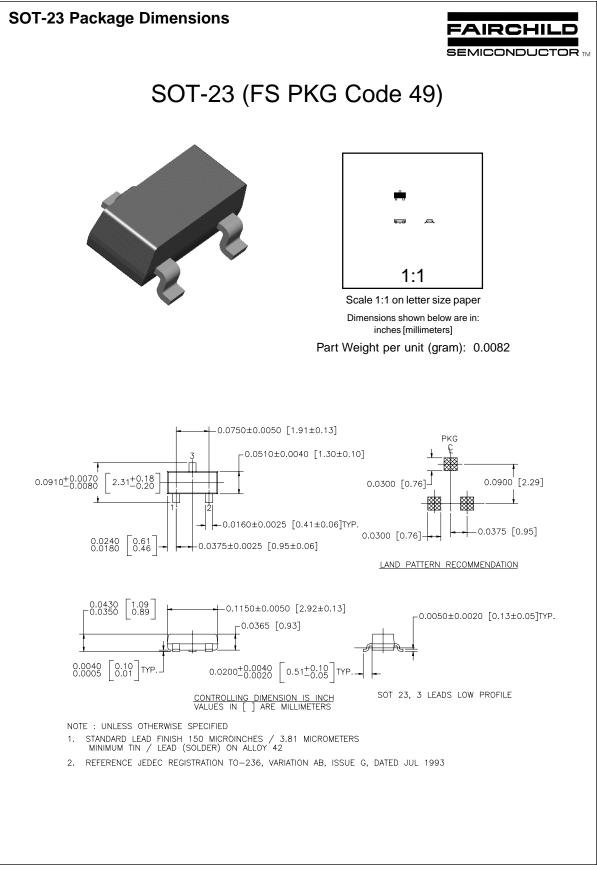


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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### PRODUCT STATUS DEFINITIONS

**Definition of Terms** 

| Datasheet Identification | Product Status            | Definition  |
|--------------------------|---------------------------|---|
| Advance Information      | Formative or<br>In Design | This datasheet contains the design specifications for<br>product development. Specifications may change in<br>any manner without notice.  |
| Preliminary              | First Production          | This datasheet contains preliminary data, and<br>supplementary data will be published at a later date.<br>Fairchild Semiconductor reserves the right to make<br>changes at any time without notice in order to improve<br>design. |
| No Identification Needed | Full Production           | This datasheet contains final specifications. Fairchild<br>Semiconductor reserves the right to make changes at<br>any time without notice in order to improve design.   |
| Obsolete                 | Not In Production         | This datasheet contains specifications on a product<br>that has been discontinued by Fairchild semiconductor.<br>The datasheet is printed for reference information only.   |
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